

#### **HORIZONTAL DEFLECTION POWER TRANSISTORS**

...specifically designed for use in larg screen color deflection circuits.

#### **FEATURES:**

- \* High Voltage: V<sub>CBO</sub>=1500V

  \* Low Saturation Voltage :V<sub>CE(sat)</sub>=5.0V(Max.) @ I<sub>C</sub> = 4.0 A

  \* High Speed :t<sub>f</sub> =1.0 us(Max.) @ I<sub>CP</sub> =4.0 A, I<sub>B1</sub> = 0.8A

  \* Built-in Damper Type

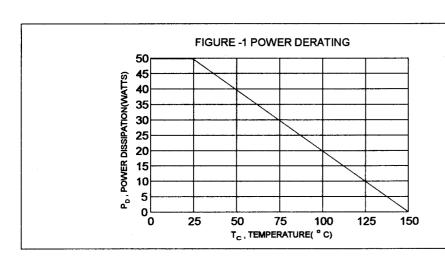
- \* Glass Passivated Collector-Base Junction

#### **MAXIMUM RATINGS**

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V <sub>CBO</sub>	1500	V
Collector-Emitter Voltage	V <sub>CEO</sub>	600	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	V
Collector Current-Continuous	Ic	5.0	А
Base Current	IB	2.5	А
Total Power Dissipation @T <sub>C</sub> =25°C Derate above 25°C	P <sub>D</sub>	50 0.4	W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	- 65 to +150	°C

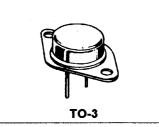
### THERMAL CHARACTERISTICS

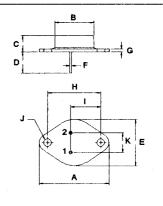
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	Rejc	2.5	°C/W



## **NPN** 2SD870

5 AMPERE **POWER TRANSISTORS 1500 VOLTS** 50 WATTS





PIN 1.BASE 2.EMITTER COLLECTOR(CASE)

DIM	MILLIMETERS			
Dilvi	MIN	MAX		
Α	38.75	39.96		
В	19.28	22.23		
С	7.96	9.28		
D	11.18	12.19		
Ε	25.20	26.67		
F	0.92	1.09		
G	1.38	1.62		
Н	29.90	30.40		
1	16.64	17.30		
J	3.88	4.36		
K	10.67	11.18		

Unit

# **ELECTRICAL CHARACTERISTICS** ( $T_c = 25^{\circ}\text{C}$ unless otherwise noted )

OFF CHARACTERISTICS				
Collector Cutoff Current (V <sub>CB</sub> =500 V, I <sub>E</sub> = 0 )	Ісво		10	uA
Emitter-Base Voltage (I <sub>E</sub> = 200 mA, I <sub>C</sub> = 0 )	V <sub>EBO</sub>	5.0		V

Symbol

Min

Max

## **ON CHARACTERISTICS (1)**

Characteristic

DC Current Gain ( I <sub>C</sub> = 1.0 A , V <sub>CE</sub> = 5.0 V )	hFE	8.0		
Collector - Emitter Saturation Voltage ( I <sub>C</sub> = 4.0 A, I <sub>B</sub> = 0.8 A )	V <sub>CE(sat)</sub>		5.0	V
Base - Emitter Saturation Voltage (I <sub>C</sub> = 4.0 A, I <sub>B</sub> = 0.8 A)	V <sub>BE(sat)</sub>		1.5	٧
Forward Voltage (Damper Diode) (IF=5.0 A )	-V <sub>F</sub>		2.0	٧

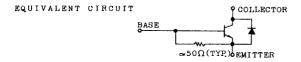
## **DYNAMIC CHARACTERISTICS**

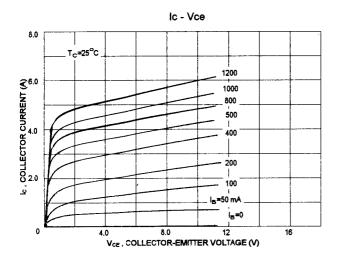
Current Gain - Bandwidth Product (I <sub>C</sub> = 0.1 A, V <sub>CE</sub> = 10 V, f = 1.0 MHz)	f <sub>T</sub>	3.0(Typ)	MHz
Collector Output Capacitance (V <sub>CB</sub> =10 V, I <sub>E</sub> = 0, f = 1.0 MHz)	Cob	170(Typ)	pF

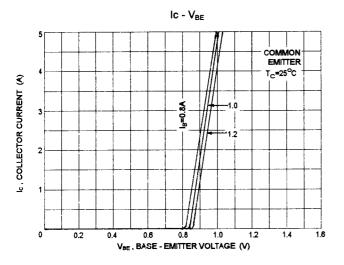
### **SWITCHING CHARATERISTICS**

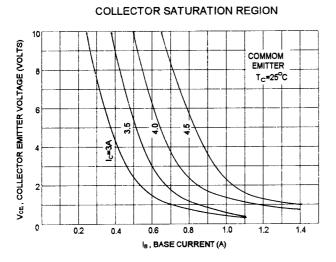
			 <del></del>	
Fall Time	I <sub>C</sub> = 4.0A ,I <sub>B1</sub> (end)=0.8A	tf	1.0	μs

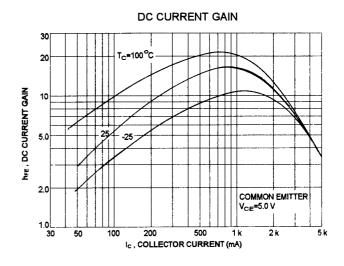
(1) Pulse Test: Pulse width  $\leq 300 \, \mu s$  , Duty Cycle  $\leq 2.0\%$ 



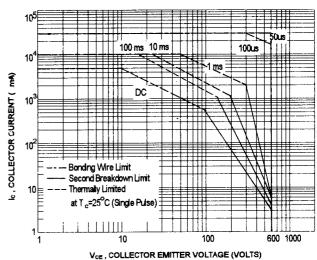








## ACTIVE-REGION SAFE OPERATING AREA (SOA)



There are two limitation on the power handling ability of a transistor:average junction temperature and second breakdown safe operating area curves indicate  $I_{\rm C^-}V_{\rm CE}$  limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of SOA curve is base on  $T_{J(PK)}$ =150 °C; $T_C$  is variable depending on conditions, second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(PK)}$ ≤150°C,At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



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